NSN 5962-01-339-7622

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View Online at https://aerobasegroup.com/nsn/5962-01-339-7622

Overall Height:
0.400 inches
Body Length:
1.060 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
2.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar and programmable and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
D-8 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes output sink
Terminal Surface Treatment:
Solder
Product Name:
And-or invert gate array
Voltage Rating And Type Per Characteristic:
-500.0 millivolts power source and 12.0 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, high to low level output and 50.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:
Programmable
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit

N/a

Shelf Life:

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Demilitarization:

Yes - demil/mli

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